

## High-Entropy Dielectric Relaxors: A New Frontier in Energy Storage Technology

Prof D Pamu

Dielectric capacitors, fundamental to high/pulsed power electronic devices, find extensive applications in fields like hybrid electric vehicles, microwave communications, and distributed power systems. Their popularity stems from their high-power density and ultra-fast charge/discharge rates[1]. Unlike batteries and solid oxide fuel cells that store energy through chemical reactions, dielectric capacitors store energy by displacing bound charged elements. The design of high-performance, lead-free energy storage capacitors holds significant promise in the global market, particularly with the growing emphasis on environmental protection. These capacitors are essential for advanced electronic and electrical power systems[2], [3]. However, their relatively low energy storage capability compared to electrochemical devices like batteries poses a challenge, hindering advanced devices' miniaturization, integration, and cost-effectiveness. Significant efforts have been directed towards developing high-energy-density, high-efficiency, and reliable dielectrics. Nonlinear ferroelectric dielectrics with substantial spontaneous polarization, such as  $\text{Pb}(\text{ZrTi})\text{O}_3$ ,  $\text{BiTiO}_3$ , and  $\text{Bi}_4\text{Ti}_3\text{O}_{12}$ , have been used to achieve a high maximum polarization ( $P_m$ )[4]. To achieve a low remnant polarization ( $P_r$ ), researchers have explored element doping, solid solutions, and fabrication parameter modifications to disrupt long-range ferroelectric domains, lower polarization switching barriers, and reduce polarization hysteresis. Also, nanostructure modification, thickness optimization, grain refinement, and defect engineering have enhanced the breakdown strength ( $E_b$ ). By strategically combining these methods to optimize dielectric parameters, energy densities ( $U_e$ ) of up to approximately  $150 \text{ J cm}^{-3}$  have been recently achieved.

Recently, high-entropy materials, where multiple elements occupy equivalent lattice sites, have been shown to significantly enhance various functionalities, such as thermoelectrics, batteries, and catalysts [5]. This improvement is attributed to entropy-dominated

phase stabilization, an atomic disorder with lattice distortion, sluggish diffusion kinetics, and the synergistic properties of multiple components. The high-entropy concept offers a promising strategy for enhancing dielectric energy performance.

### **Design of high-entropy stabilized Bi<sub>4</sub>Ti<sub>3</sub>O<sub>12</sub> based dielectric ceramics and thin film**

We will design high-entropy dielectrics relaxors starting from the ferroelectric Bi<sub>4</sub>Ti<sub>3</sub>O<sub>12</sub> by introducing equimolar-ratio Zr, Ho and Sn elements into the Ti sites, and Sr into the Bi sites with the nominal composition of  $(Bi_{4-x}Sr_x)(Ti_{3-3y}Zr_yHo_ySn_y)O_{12}$  ( $x=(0-2, \Delta=0.5), y=(0-1, \Delta=0.5)$ ). We investigate the electronic structure, dielectric properties, and energy storage capacities of these high-entropy dielectric relaxors.

### **Reference**

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